

**Notice of References Cited**Application No.  
**09/305,121**

Applicant(s)

**Gunapala et al.**Examiner  
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**2815**

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**U.S. PATENT DOCUMENTS**

	DOCUMENT NO.	DATE	NAME	CLASS	SUBCLASS
A	5,646,421	7/1997	Liu	257	21
B	5,023,685	6/1991	Bethea et al.	357	30
C					
D					
E					
F					
G					
H					
I					
J					
K					
L					
M					

**FOREIGN PATENT DOCUMENTS**

	DOCUMENT NO.	DATE	COUNTRY	NAME	CLASS	SUBCLASS
N						
O						
P						
Q						
R						
S						
T						

**NON-PATENT DOCUMENTS**

	DOCUMENT (Including Author, Title, Source, and Pertinent Pages)	DATE
u	Tsai et al., "Two-color infrared photodetector using GaAs/AlGaAs and strained InGaAs/AlGaAs multiquantum wells," Appl. Phys. Lett, 62 (26), 28 June 1993, pages 3504-3506.	6/1993
v	Tidrow et al., "Grating coupled multicolor quantum well infrared photodetectors," Appl. Phys. Lett, 67 (13), 25 September 1995, pages 1800-1802.	9/1995
w	Tidrow et al., "A high strain two-stack two-color quantum well infrared photodetector," Appl. Phys. Lett, 70 (7), 17 February 1997, pages 859-861.	2/1997
x	Fiore et al., "Strained InGaAs/AlGaAs quantum well infrared detectors at 4.5 microns," Appl. Phys. Lett, 64 (4), 24 January 1994, pages 478-480.	1/1994